TOSHIBA Power Transistor Module Silicon PNP Epitaxial Type (Four Darlington Power Transistors in One)

MP4305

High Power Switching Applications

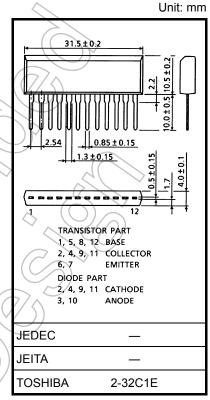
Hammer Drive, Pulse Motor Drive and Inductive Load Switching

- Small package by full molding (SIP 12 pin)
- High collector power dissipation (4 devices operation)
 PT = 4.4 W (Ta = 25°C)
- High collector current: $I_{C(DC)} = -5 A \text{ (max)}$
- High DC current gain: $h_{FE} = 2000$ (min) ($V_{CE} = -5$ V, $I_{C} = -3$ A)
- Diode included for absorbing fly-back voltage

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V _{CBO}	-100	> ∨
Collector-emitter voltage		V _{CEO}	-100	V
Emitter-base voltage		V _{EBO}	-6	V
Collector current	DC	Ic	-5	
	Pulse	ICP	-8	A
Continuous base current		IB	-0.5	Α
Collector power dissipation (1-device operation)		(Pc)	2.2	w
Collector power dissipation (4-device operation)		Рт	4.4	M
Junction temperature		\mathcal{I}_{j}	150	ပ္
Storage temperature range		T _{stg}	-55 to 150	°C

Industrial Applications

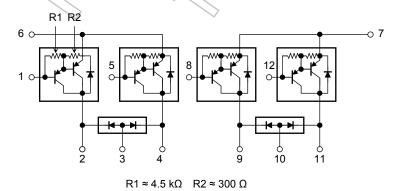


Weight: 3.9 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

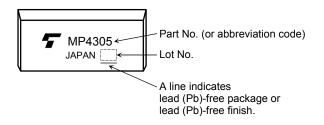
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Array Configuration



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Marking



Thermal Characteristics

Characteristics	Symbol	Max	Unit	
Thermal resistance from junction to ambient	ΣR _{th (j-a)}	28.4	°C/W	
(4-device operation, Ta = 25°C)	3 /			
Maximum lead temperature for soldering purposes	TL	260	°C (
(3.2 mm from case for 10 s)				

Electrical Characteristics (Ta = 25°C)

				\sim		1	
Charac	teristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off cu	rrent	I _{CBO} <	V _{CB} = -100 V, I _E = 0 A	_	_	-10	μΑ
Collector cut-off cu	rrent	ICEO	V _{CE} = -100 V, I _B = 0 A	_	1	-10	μΑ
Emitter cut-off curre	ent	I _{EBO}	V _{EB} = -6 V, I _C = 0 A	-0.6	1	-2.0	mA
Collector-base brea	akdown voltage	V (BR) CBO	I _C = -1 mA, I _E = 0 A	-100	_	_	٧
Collector-emitter br	reakdown voltage	V _(BR) CEO	$I_C = -10 \text{ mA}, I_B = 0 \text{ A}$	-100	_	_	٧
DC current gain	(/	hFE (1)	$V_{CE} = -5 \text{ V, } I_{C} = -3 \text{ A}$	2000	_	15000	
DC current gain		h _{F∉ (2)}	V _{CE} = -5 V, I _C = -5 A	1000	_	_	_
Saturation voltage	Collector-emitter	V _{CE} (sat)	$I_C = -3 \text{ A}, I_B = -6 \text{ mA}$		_	-1.5	V
	Base-emitter	V _{BE (sat)}	I _C = -3 A, I _B = -6 mA	-		-2.0	
Transition frequence	су	ft	$V_{CE} = -2 \text{ V}, I_{C} = -0.5 \text{ A}$	-	40		MHz
Collector output ça	pacitance	C _{ob}	V _{CB} = -10 V, I _E = 0 A, f = 1 MHz		55	_	pF
Turn-on time Switching time Storage time Fall time	ton	Output Input IB2 Output		0.3	_		
	t _{stg}	20 μs I _{B1} Q	-	2.0	_	μs	
	tr	$V_{CC} = -30 \text{ V}$ $-I_{B1} = I_{B2} = 6 \text{ mA}, \text{ duty cycle} \le 1\%$	_	0.4	_		

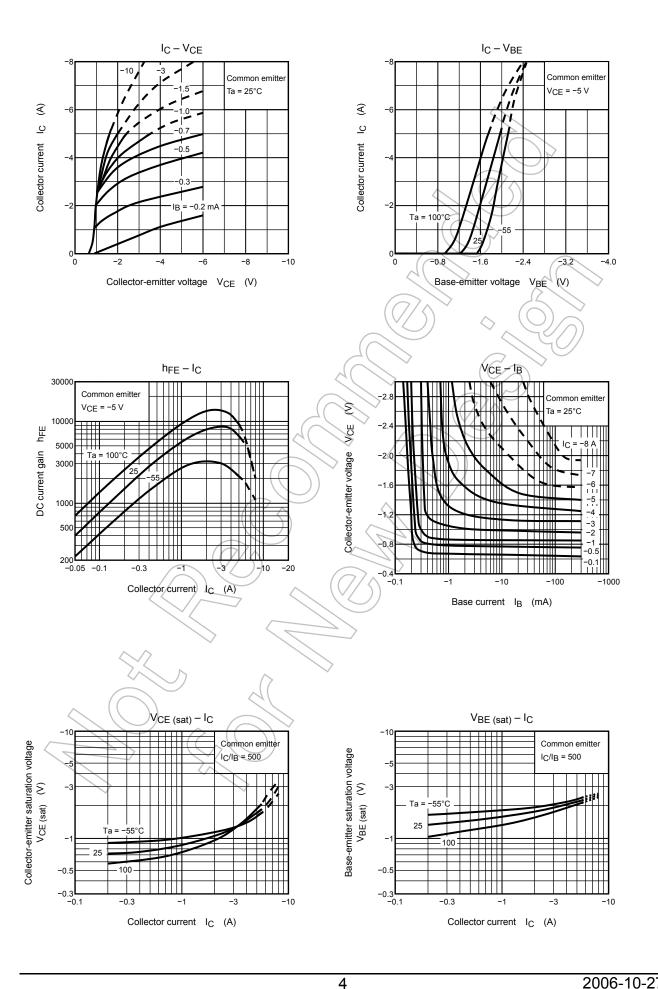
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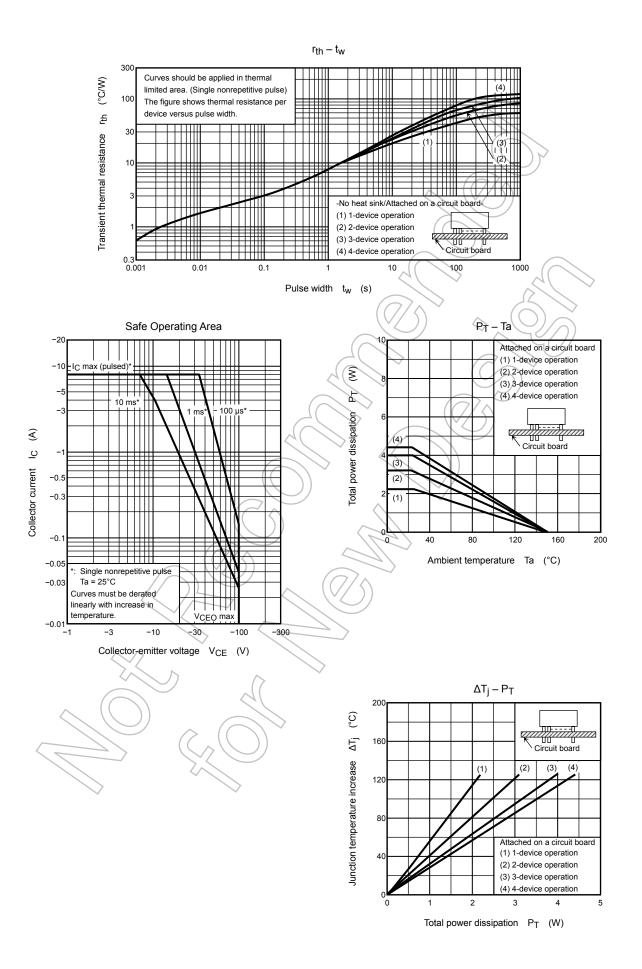
Emitter-Collector Diode Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Maximum forward current	I _{FM}	_	_	_	3	Α
Surge current	I _{FSM}	t = 1 s, 1 shot	_	_	6	Α
Forward voltage	V _F	I _F = 1 A, I _B = 0 A	/_	_	2.0	V
Reverse recovery time	t _{rr}	I _F = 3 A, V _{BE} = 3 V, dI _F /dt = −50 A/µs		1.0	_	μs
Reverse recovery charge	Q _{rr}	- 3 Λ, νΒΕ - 3 ν, αιέ/αι50 Ανμς	1) /8	_	μC

Flyback-Diode Rating and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Maximum forward current	I _{FM}		_		3	Α
Reverse current	I _R	V _R = 110 V		17	0.4	μA
Reverse voltage	V_{R}	Ι _R = 100 μΑ	100	7-//	> -	V
Forward voltage	V _F	I _F = 1 A	7-	1/5	1.5	V







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